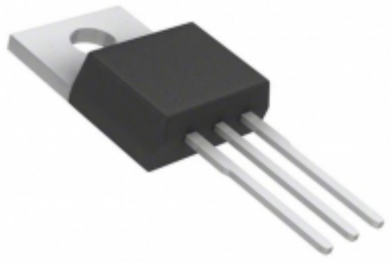



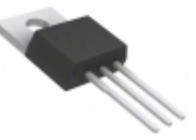



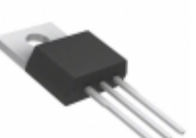
	<h2 style="color: red;">FQP33N10</h2>
	<p>Hersteller-Teilenummer: FQP33N10</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 33A TO-220</p> <p>Datenblätter: 1.FQP33N10.pdf 2.FQP33N10.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 151658 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP33N10
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 33A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	151658 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	127W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	33A (Tc)
Rds On (Max) @ Id, Vgs	52 mOhm @ 16.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	51nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube

FQP33N10 ist neu im Original, Suche FQP33N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP33N10 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP33N10: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP32N20C_F080 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>	 <p>FQP34N20L Fairchild/ON Semiconductor MOSFET N-CH 200V 31A TO-220</p>	 <p>FQP33N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>	 <p>FQP33N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>
 <p>FQP33N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 33A TO-220</p>	 <p>FQP32N20C AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>	 <p>FQP32N20C_F080 Fairchild/ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>	 <p>FQP32N20C Fairchild/ON Semiconductor MOSFET N-CH 200V 28A TO-220</p>

heiße Teile

Mehr

⊗ FQP22N30	↔ FQP22P10	⇒ FQP22P10	D FQP24N08	⇒ FQP24N08
⊣ FQP24N40	⊗ FQP27N25	D FQP27N25	⇒ FQP27N60	⇒ FQP27P06
⊗ FQP27P06	⊣ FQP2N60B	⊗ FQP2N60C	↔ FQP2N60C	⇒ FQP2N65C
D FQP30N06	⊗ FQP30N06	⊣ FQP30N06L	⊗ FQP30N06L	⇒ FQP32N12V2
⇒ FQP32N12V2	↔ FQP32N20	⊗ FQP32N20C	⊣ FQP32N20C	⇒ FQP33N10
↔ FQP33N10L	⇒ FQP33N10L	D FQP34N20	⊗ FQP34N20	⊣ FQP34N20L
⊗ FQP34N20L	D FQP3N50C	⇒ FQP3N60C	↔ FQP3N60C	⇒ FQP3N80C
⊣ FQP3N80C	⊗ FQP44N08	↔ FQP44N08	⇒ FQP44N10	⇒ FQP44N10
⊗ FQP44N10F	⊣ FQP44N10F	⊗ FQP45N03L	D FQP45N03LM	⇒ FQP45N15V2
↔ FQP45N15V2	⊗ FQP45N20A	⊣ FQP46N15	⊗ FQP46N15	⇒ FQP47N06

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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